NSN 5961-01-060-6663

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-060-6663 **Inclosure Material:** Ceramic and metal **Overall Length:** 0.520 inches **End Application:** Airport surveillance radar (asr-9); next generation radar (nexrad) **Mounting Method:** Press fit **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1300.0 on-state voltage, dc **Current Rating Per Characteristic:** 100.00 milliamperes drain current peak **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Nsn restricted to use by nws depot team only **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** Yes - demil/mli Fiig: A110a0